



Product Summary

BV _{DSS}	RDS(ON) MAX	Id мах @Ta = +25°С
-20V	0.75Ω @ V _{GS} = -4.5V	-0.63A
-20 V	1.05Ω @ V _{GS} = -2.5V	-0.54A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Power Supply Converter Circuits

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Complementary Pair MOSFET Ultra-Small Surface Mount Package
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3) For automotive applications requiring specific change control
- (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

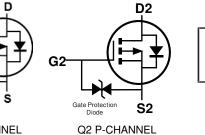
- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 @3)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)

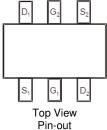






Top View Q1 P-CHANNEL





Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2900UDW-7	SOT363	3,000/Tape & Reel
DMP2900UDW-13	SOT363	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

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BI	D2	Ϋ́Ι	М	
Ν	ΙŸ	20	В	

BD2 = Product Type Marking Code

- YM = Date Code Marking
- \overline{Y} = Year (ex: I = 2021)

M = Month (ex: 9 = September)

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Notes:

Dale Code Key												
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н	Ι	J	K	L	М	N	0	Р	R	S	Т
	т										T 1	
Mar and In												
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteris	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-20	V		
Gate-Source Voltage	VGSS	±6	V		
Continuous Drain Current (Note 6) V _{GS} = -4.5V Steady State		TA = +25°C TA = +70°C	lo	-0.63 -0.5	А
Maximum Continuous Body Diode Forward Current	ls	-0.42	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	Ідм	-2.5	А		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

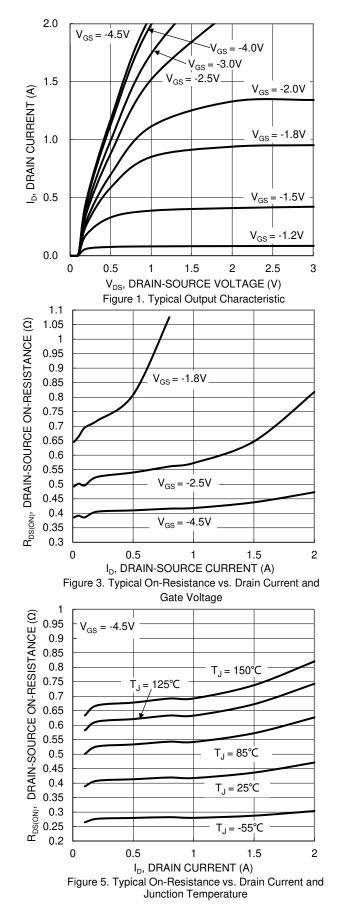
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	0.37	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	340	°C/W
Total Power Dissipation (Note 6)	TA = +25°C	PD	0.46	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	272	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

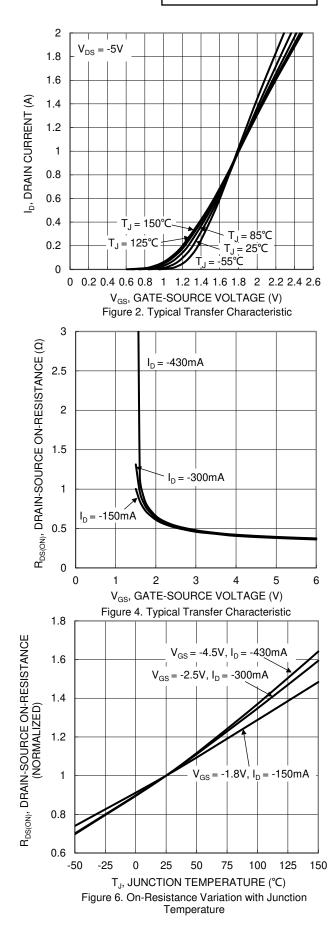
Electrical Characteristics (T_A = +25°C, V_{BIAS} = 5V, V_{IN} = 1.05V, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	-20	—	_	V	$V_{GS} = 0V, I_{D} = -250 \mu A$	
Zero Gate Voltage Drain Current @T _C = +25°C	IDSS	_	—	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	—	±2.0	μA	$V_{GS} = \pm 4.5 V$, $V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-0.5	—	-1.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
			0.4	0.75		$V_{GS} = -4.5V, I_D = -430mA$	
Static Drain-Source On-Resistance	RDS(ON)	_	0.53	1.05	Ω	V _{GS} = -2.5V, I _D = -300mA	
			0.7	1.5		$V_{GS} = -1.8V, I_D = -150mA$	
Diode Forward Voltage (Note 7)	V _{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_S = -150mA$	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	Ciss	_	49	—	pF		
Output Capacitance	Coss	_	12	_	pF	V _{DS} = -16V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	3.4	_	pF		
Total Gate Charge	Qg	_	0.7	_	nC		
Gate-Source Charge	Qgs	_	0.1	_	nC	VGS = -4.5V, VDS = -10V, ID = -250mA	
Gate-Drain Charge	Q _{gd}	_	0.1	_	nC	1D = -25011A	
Turn-On Delay Time	t _{D(ON)}		16	—	ns		
Turn-On Rise Time	t _R	_	15	—	ns	$V_{DS} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	tD(OFF)		213	_	ns	R _g = 10Ω, R _L = 47Ω ID = -200mA	
Turn-Off Fall Time	tF	_	89	—	ns		
Reverse Recovery Time	trr	—	10.5	—	ns	I _F = 1A. di/dt = 100A/µs	
Reverse Recovery Charge	Q _{RR}	_	1.8	_	nC	$r = rA$, $u/ut = rooA/\mu s$	

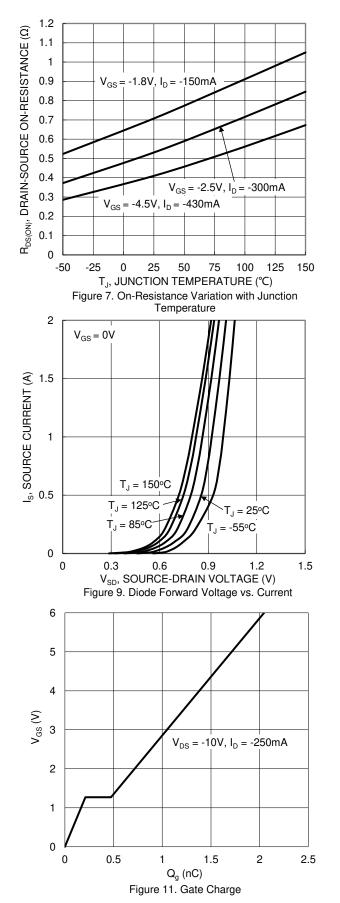
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

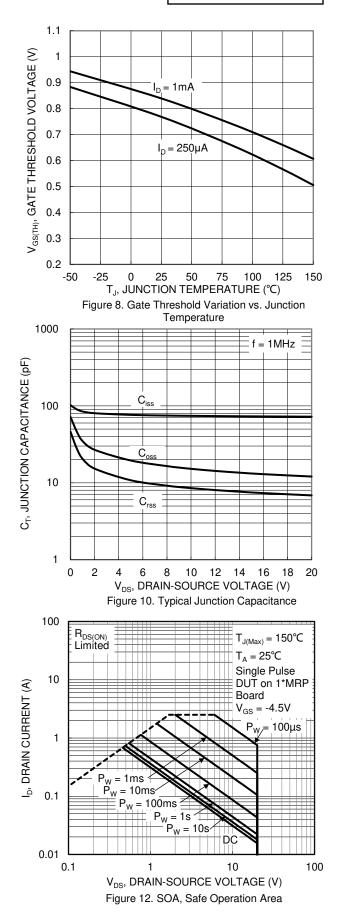




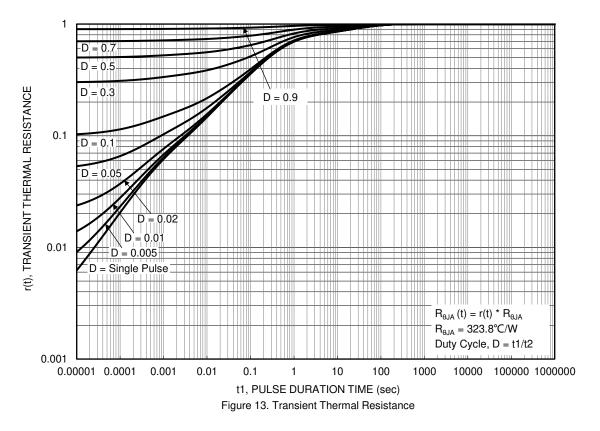








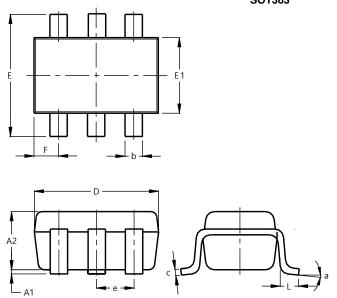






Package Outline Dimensions

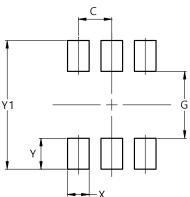
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.10	0.30	0.25					
С	0.10	0.22	0.11					
D	1.80	2.20	2.15					
ш	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C).650 E	SC					
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All I	Dimen	sions	in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500

SOT363



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